

Micron UFS 4.0 storage delivers the industry's fastest performance¹ for flagship smartphone user experiences

Up to 4300 MBps sequential read speeds

Up to 4000 MBps sequential write speeds

Technology innovation for next-generation mobile performance

Delivering the world's leading mobile storage solutions

Best-in-class

- Available in capacities up to 1TB
- Designed on advanced 232-layer 3D NAND technology
- Six-plane architecture² for higher bandwidth use cases
- Optimized for AI and 5G applications

Industry's fastest UFS 4.0

Backed by superior performance and power efficiency capabilities

0% faster app launches³

better power efficiency³

20% faster bootup speed³

write latency advantage vs. competition¹

Vertical integration for unrivaled quality

UFS 4.0 with an optimized, dependable and high-quality storage solution for smartphones



storage leadership



Internally developed controller that is highly configurable and secure



Vertically integrated ensuring a dependable supply chain



Reliable hardware and ultra-secure firmware lets you qualify with confidence

To learn more about Micron's best-in-class UFS 4.0, visit

Unlock the potential of UFS 4.0

micron.com/ufs

¹ as compared to publicly available UFS 4.0 products performance, the statement is based on benchmark testing conducted in Micron labs ² for 512GB and 1TB only

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³ as compared to previous generation UFS 3.1